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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Not For New Designs
Core Processor	M32C/80
Core Size	16/32-Bit
Speed	32MHz
Connectivity	CANbus, I ² C, IEBus, SIO, UART/USART
Peripherals	DMA, PWM, WDT
Number of I/O	85
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	24K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 26x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LFQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/m30843fjgp-u3

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Table 1.4 Pin Characteristics for 144-Pin Package (Continued)

Pin No.	Control Pin	Port	Interrupt Pin	Timer Pin	UART/CAN Pin	Intelligent I/O Pin	Analog Pin	Bus Control Pin
49		P13 ₆						
50		P13 ₅						
51		P13 ₄						
52		P5 ₇						$\overline{\text{RDY}}$
53		P5 ₆						$\overline{\text{ALE}}$
54		P5 ₅						$\overline{\text{HOLD}}$
55		P5 ₄						$\overline{\text{HLDA/ALE}}$
56		P13 ₃						
57	V _{SS}							
58		P13 ₂						
59	V _{CC2}							
60		P13 ₁						
61		P13 ₀						
62		P5 ₃						$\overline{\text{CLKOUT/BCLK/ALE}}$
63		P5 ₂						$\overline{\text{RD}}$
64		P5 ₁						$\overline{\text{WRH/BHE}}$
65		P5 ₀						$\overline{\text{WRL/WR}}$
66		P12 ₇						
67		P12 ₆						
68		P12 ₅						
69		P4 ₇						$\overline{\text{CS0/A23}}$
70		P4 ₆						$\overline{\text{CS1/A22}}$
71		P4 ₅						$\overline{\text{CS2/A21}}$
72		P4 ₄						$\overline{\text{CS3/A20}}$
73		P4 ₃						A ₁₉
74	V _{CC2}							
75		P4 ₂						A ₁₈
76	V _{SS}							
77		P4 ₁						A ₁₇
78		P4 ₀						A ₁₆
79		P3 ₇						A ₁₅ (/D ₁₅)
80		P3 ₆						A ₁₄ (/D ₁₄)
81		P3 ₅						A ₁₃ (/D ₁₃)
82		P3 ₄						A ₁₂ (/D ₁₂)
83		P3 ₃						A ₁₁ (/D ₁₁)
84		P3 ₂						A ₁₀ (/D ₁₀)
85		P3 ₁						A ₉ (/D ₉)
86		P12 ₄						
87		P12 ₃						
88		P12 ₂						
89		P12 ₁						
90		P12 ₀						
91	V _{CC2}							
92		P3 ₀						A ₈ (/D ₈)
93	V _{SS}							
94		P2 ₇					AN2 ₇	A ₇ (/D ₇)
95		P2 ₆					AN2 ₆	A ₆ (/D ₆)
96		P2 ₅					AN2 ₅	A ₅ (/D ₅)

NOTES:

1. Bus control pins in M32C/84T cannot be used.

Table 1.5 Pin Characteristics for 100-Pin Package

Package Pin No.		Control Pin	Port	Interrupt Pin	Timer Pin	UART/CAN Pin	Intelligent I/O Pin	Analog Pin	Bus Control Pin ⁽¹⁾
FP	GP								
1	99		P96			TxD4/SDA4/SRxD4		ANEX1	
2	100		P95			CLK4		ANEX0	
3	1		P94		TB4IN	CTS4/RTS4/SS4		DA1	
4	2		P93		TB3IN	CTS3/RTS3/SS3		DA0	
5	3		P92		TB2IN	TxD3/SDA3/SRxD3			
6	4		P91		TB1IN	RxD3/SCL3/STxD3			
7	5		P90		TB0IN	CLK3			
8	6	BYTE							
9	7	CNVss							
10	8	XCIN	P87						
11	9	XCOUT	P86						
12	10	RESET							
13	11	XOUT							
14	12	Vss							
15	13	XIN							
16	14	VCC1							
17	15		P85	NMI					
18	16		P84	INT2					
19	17		P83	INT1		CAN0IN			
20	18		P82	INT0		CAN0OUT			
21	19		P81		TA4IN/U		INPC15/OUTC15		
22	20		P80		TA4OUT/U		ISRxD0		
23	21		P77		TA3IN	CAN0IN	INPC14/OUTC14/ISCLK0		
24	22		P76		TA3OUT	CAN0OUT	INPC13/OUTC13/ISTxD0		
25	23		P75		TA2IN/W		INPC12/OUTC12/ISRxD1/BE1IN		
26	24		P74		TA2OUT/W		INPC11/OUTC11/ISCLK1		
27	25		P73		TA1IN/V	CTS2/RTS2/SS2	INPC10/OUTC10/ISTxD1/BE1OUT		
28	26		P72		TA1OUT/V	CLK2			
29	27		P71		TB5IN/TA0IN	RxD2/SCL2/STxD2	INPC17/OUTC17		
30	28		P70		TA0OUT	TxD2/SDA2/SRxD2	INPC16/OUTC16		
31	29		P67			TxD1/SDA1/SRxD1			
32	30		P66			RxD1/SCL1/STxD1			
33	31		P65			CLK1			
34	32		P64			CTS1/RTS1/SS1			
35	33		P63			TxD0/SDA0/SRxD0			
36	34		P62			RxD0/SCL0/STxD0			
37	35		P61			CLK0			
38	36		P60			CTS0/RTS0/SS0			
39	37		P57						RDY
40	38		P56						ALE
41	39		P55						HOLD
42	40		P54						HLDA/ALE
43	41		P53						CLKout/BCLK/ALE
44	42		P52						RD
45	43		P51						WRH/BHE
46	44		P50						WRL/WR
47	45		P47						CS0/A23
48	46		P46						CS1/A22
49	47		P45						CS2/A21
50	48		P44						CS3/A20

NOTES:

1. Bus control pins in M32C/84T cannot be used.

1.6 Pin Description

Table 1.6 Pin Description (100-Pin and 144-Pin Packages)

Classification	Symbol	I/O Type	Supply Voltage	Function
Power Supply	VCC1, VCC2 VSS	I	–	Apply 3.0 to 5.5V to both VCC1 and VCC2 pins. Apply 0V to the VSS pin. $V_{CC1} \geq V_{CC2}$ ^(1, 2)
Analog Power Supply	AVCC AVSS	I	VCC1	Supplies power to the A/D converter. Connect the AVCC pin to VCC1 and the AVSS pin to VSS
Reset Input	RESET	I	VCC1	The microcomputer is in a reset state when "L" is applied to the RESET pin
CNVSS	CNVSS	I	VCC1	Switches processor mode. Connect the CNVSS pin to VSS to start up in single-chip mode or to VCC1 to start up in microprocessor mode
Input to Switch External Data Bus Width ⁽³⁾	BYTE	I	VCC1	Switches data bus width in external memory space 3. The data bus is 16 bits wide when the BYTE pin is held "L" and 8 bits wide when it is held "H". Set to either. Connect the BYTE pin to VSS to use the microcomputer in single-chip mode
Bus Control Pins ⁽³⁾	D0 to D7	I/O	VCC2	Inputs and outputs data (D0 to D7) while accessing an external memory space with separate bus
	D8 to D15	I/O	VCC2	Inputs and outputs data (D8 to D15) while accessing an external memory space with 16-bit separate bus
	A0 to A22	O	VCC2	Outputs address bits A0 to A22
	A ₂₃	O	VCC2	Outputs inversed address bit A23
	A0/D0 to A7/D7	I/O	VCC2	Inputs and outputs data (D0 to D7) and outputs 8 low-order address bits (A0 to A7) by time-sharing while accessing an external memory space with multiplexed bus
	A8/D8 to A15/D15	I/O	VCC2	Inputs and outputs data (D8 to D15) and outputs 8 middle-order address bits (A8 to A15) by time-sharing while accessing an external memory space with 16-bit multiplexed bus
	CS0 to CS3	O	VCC2	Outputs CS0 to CS3 that are chip-select signals specifying an external space
	WRL / WR WRH / BHE RD	O	VCC2	Outputs WRL, WRH, (WR, BHE) and RD signals. WRL and WRH can be switched with WR and BHE by program ■ WRL, WRH and RD selected: If external data bus is 16 bits wide, data is written to an even address in external memory space when WRL is held "L". Data is written to an odd address when WRH is held "L". Data is read when RD is held "L". ■ WR, BHE and RD selected: Data is written to external memory space when WR is held "L". Data in an external memory space is read when RD is held "L". An odd address is accessed when BHE is held "L". Select WR, BHE and RD for external 8-bit data bus.
	ALE	O	VCC2	ALE is a signal latching the address
	HOLD	I	VCC2	The microcomputer is placed in a hold state while the HOLD pin is held "L"
	HLDA	O	VCC2	Outputs an "L" signal while the microcomputer is placed in a hold state
	RDY	I	VCC2	Bus is placed in a wait state while the RDY pin is held "L"

I : Input O : Output I/O : Input and output

NOTES:

1. VCC1 is hereinafter referred to as VCC unless otherwise noted.
2. Apply 4.2 to 5.5V to the VCC1 and VCC2 pins when using M32C/84T. $V_{CC1}=V_{CC2}$.
3. Bus control pins in M32C/84T cannot be used.

4. Special Function Registers (SFR)

Address	Register	Symbol	Value after RESET
0000 ₁₆			
0001 ₁₆			
0002 ₁₆			
0003 ₁₆			
0004 ₁₆	Processor Mode Register 0 ⁽¹⁾	PM0	1000 0000 ₂ (CNVss pin ="L") 0000 0011 ₂ (CNVss pin ="H")
0005 ₁₆	Processor Mode Register 1	PM1	00 ₁₆
0006 ₁₆	System Clock Control Register 0	CM0	0000 1000 ₂
0007 ₁₆	System Clock Control Register 1	CM1	0010 0000 ₂
0008 ₁₆			
0009 ₁₆	Address Match Interrupt Enable Register	AIER	00 ₁₆
000A ₁₆	Protect Register	PRCR	XXXX 0000 ₂
000B ₁₆	External Data Bus Width Control Register ⁽²⁾	DS	XXXX 1000 ₂ (BYTE pin ="L") XXXX 0000 ₂ (BYTE pin ="H")
000C ₁₆	Main Clock Division Register	MCD	XXX0 1000 ₂
000D ₁₆	Oscillation Stop Detection Register	CM2	00 ₁₆
000E ₁₆	Watchdog Timer Start Register	WDTs	XX ₁₆
000F ₁₆	Watchdog Timer Control Register	WDC	000X XXXX ₂
0010 ₁₆	Address Match Interrupt Register 0	RMAD0	000000 ₁₆
0011 ₁₆			
0012 ₁₆			
0013 ₁₆	Processor Mode Register 2	PM2	00 ₁₆
0014 ₁₆	Address Match Interrupt Register 1	RMAD1	000000 ₁₆
0015 ₁₆			
0016 ₁₆			
0017 ₁₆	Voltage Detection Register 2 ⁽²⁾	VCR2	00 ₁₆
0018 ₁₆	Address Match Interrupt Register 2	RMAD2	000000 ₁₆
0019 ₁₆			
001A ₁₆			
001B ₁₆	Voltage Detection Register 1 ⁽²⁾	VCR1	0000 1000 ₂
001C ₁₆	Address Match Interrupt Register 3	RMAD3	000000 ₁₆
001D ₁₆			
001E ₁₆			
001F ₁₆			
0020 ₁₆			
0021 ₁₆			
0022 ₁₆			
0023 ₁₆			
0024 ₁₆			
0025 ₁₆			
0026 ₁₆	PLL Control Register 0	PLC0	0001 X010 ₂
0027 ₁₆	PLL Control Register 1	PLC1	000X 0000 ₂
0028 ₁₆	Address Match Interrupt Register 4	RMAD4	000000 ₁₆
0029 ₁₆			
002A ₁₆			
002B ₁₆			
002C ₁₆	Address Match Interrupt Register 5	RMAD5	000000 ₁₆
002D ₁₆			
002E ₁₆			
002F ₁₆	Voltage Down Detection Interrupt Register ⁽²⁾	D4INT	00 ₁₆

X: Indeterminate

Blank spaces are reserved. No access is allowed.

NOTES:

1. The PM01 and PM00 bits in the PM1 register maintain values set before reset even if software reset or watchdog timer reset is performed.
2. These registers in M32C/84T cannot be used.

Address	Register	Symbol	Value after RESET
00C0 ₁₆			
00C1 ₁₆			
00C2 ₁₆			
00C3 ₁₆			
00C4 ₁₆			
00C5 ₁₆			
00C6 ₁₆			
00C7 ₁₆			
00C8 ₁₆			
00C9 ₁₆			
00CA ₁₆			
00CB ₁₆			
00CC ₁₆			
00CD ₁₆			
00CE ₁₆			
00CF ₁₆			
00D0 ₁₆			
00D1 ₁₆			
00D2 ₁₆			
00D3 ₁₆			
00D4 ₁₆			
00D5 ₁₆			
00D6 ₁₆			
00D7 ₁₆			
00D8 ₁₆			
00D9 ₁₆			
00DA ₁₆			
00DB ₁₆			
00DC ₁₆			
00DD ₁₆			
00DE ₁₆			
00DF ₁₆			
00E0 ₁₆			
00E1 ₁₆			
00E2 ₁₆			
00E3 ₁₆			
00E4 ₁₆			
00E5 ₁₆			
00E6 ₁₆			
00E7 ₁₆			
00E8 ₁₆ 00E9 ₁₆	SI/O Receive Buffer Register 0	G0RB	XXXX XXXX ₂ X000 XXXX ₂
00EA ₁₆ 00EB ₁₆	Transmit Buffer/Receive Data Register 0	G0TB/G0DR	XX ₁₆
00EC ₁₆	Receive Input Register 0	G0RI	XX ₁₆
00ED ₁₆	SI/O Communication Mode Register 0	G0MR	00 ₁₆
00EE ₁₆	Transmit Output Register 0	G0TO	XX ₁₆
00EF ₁₆	SI/O Communication Control Register 0	G0CR	0000 X011 ₂

X: Indeterminate

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Address	Register	Symbol	Value after RESET
00F0 ₁₆	Data Compare Register 00	G0CMP0	XX ₁₆
00F1 ₁₆	Data Compare Register 01	G0CMP1	XX ₁₆
00F2 ₁₆	Data Compare Register 02	G0CMP2	XX ₁₆
00F3 ₁₆	Data Compare Register 03	G0CMP3	XX ₁₆
00F4 ₁₆	Data Mask Register 00	G0MSK0	XX ₁₆
00F5 ₁₆	Data Mask Register 01	G0MSK1	XX ₁₆
00F6 ₁₆	Communication Clock Select Register	CCS	XXXX 0000 ₂
00F7 ₁₆			
00F8 ₁₆	Receive CRC Code Register 0	G0RCRC	XX ₁₆
00F9 ₁₆			XX ₁₆
00FA ₁₆	Transmit CRC Code Register 0	G0TCRC	00 ₁₆
00FB ₁₆			00 ₁₆
00FC ₁₆	SI/O Extended Mode Register 0	G0EMR	00 ₁₆
00FD ₁₆	SI/O Extended Receive Control Register 0	G0ERC	00 ₁₆
00FE ₁₆	SI/O Special Communication Interrupt Detect Register 0	G0IRF	00 ₁₆
00FF ₁₆	SI/O Extended Transmit Control Register 0	G0ETC	0000 0XXX ₂
0100 ₁₆	Time Measurement/Waveform Generating Register 10	G1TM0/G1PO0	XX ₁₆
0101 ₁₆			XX ₁₆
0102 ₁₆	Time Measurement/Waveform Generating Register 11	G1TM1/G1PO1	XX ₁₆
0103 ₁₆			XX ₁₆
0104 ₁₆	Time Measurement/Waveform Generating Register 12	G1TM2/G1PO2	XX ₁₆
0105 ₁₆			XX ₁₆
0106 ₁₆	Time Measurement/Waveform Generating Register 13	G1TM3/G1PO3	XX ₁₆
0107 ₁₆			XX ₁₆
0108 ₁₆	Time Measurement/Waveform Generating Register 14	G1TM4/G1PO4	XX ₁₆
0109 ₁₆			XX ₁₆
010A ₁₆	Time Measurement/Waveform Generating Register 15	G1TM5/G1PO5	XX ₁₆
010B ₁₆			XX ₁₆
010C ₁₆	Time Measurement/Waveform Generating Register 16	G1TM6/G1PO6	XX ₁₆
010D ₁₆			XX ₁₆
010E ₁₆	Time Measurement/Waveform Generating Register 17	G1TM7/G1PO7	XX ₁₆
010F ₁₆			XX ₁₆
0110 ₁₆	Waveform Generating Control Register 10	G1POCR0	0000 X000 ₂
0111 ₁₆	Waveform Generating Control Register 11	G1POCR1	0X00 X000 ₂
0112 ₁₆	Waveform Generating Control Register 12	G1POCR2	0X00 X000 ₂
0113 ₁₆	Waveform Generating Control Register 13	G1POCR3	0X00 X000 ₂
0114 ₁₆	Waveform Generating Control Register 14	G1POCR4	0X00 X000 ₂
0115 ₁₆	Waveform Generating Control Register 15	G1POCR5	0X00 X000 ₂
0116 ₁₆	Waveform Generating Control Register 16	G1POCR6	0X00 X000 ₂
0117 ₁₆	Waveform Generating Control Register 17	G1POCR7	0X00 X000 ₂
0118 ₁₆	Time Measurement Control Register 10	G1TMCR0	00 ₁₆
0119 ₁₆	Time Measurement Control Register 11	G1TMCR1	00 ₁₆
011A ₁₆	Time Measurement Control Register 12	G1TMCR2	00 ₁₆
011B ₁₆	Time Measurement Control Register 13	G1TMCR3	00 ₁₆
011C ₁₆	Time Measurement Control Register 14	G1TMCR4	00 ₁₆
011D ₁₆	Time Measurement Control Register 15	G1TMCR5	00 ₁₆
011E ₁₆	Time Measurement Control Register 16	G1TMCR6	00 ₁₆
011F ₁₆	Time Measurement Control Register 17	G1TMCR7	00 ₁₆

X: Indeterminate

Blank spaces are reserved. No access is allowed.

Address	Register	Symbol	Value after RESET
0320 ₁₆			
0321 ₁₆			
0322 ₁₆			
0323 ₁₆			
0324 ₁₆	UART3 Special Mode Register 4	U3SMR4	00 ₁₆
0325 ₁₆	UART3 Special Mode Register 3	U3SMR3	00 ₁₆
0326 ₁₆	UART3 Special Mode Register 2	U3SMR2	00 ₁₆
0327 ₁₆	UART3 Special Mode Register	U3SMR	00 ₁₆
0328 ₁₆	UART3 Transmit/Receive Mode Register	U3MR	00 ₁₆
0329 ₁₆	UART3 Bit Rate Register	U3BRG	XX ₁₆
032A ₁₆	UART3 Transmit Buffer Register	U3TB	XX ₁₆
032B ₁₆			XX ₁₆
032C ₁₆	UART3 Transmit/Receive Control Register 0	U3C0	0000 1000 ₂
032D ₁₆	UART3 Transmit/Receive Control Register 1	U3C1	0000 0010 ₂
032E ₁₆	UART3 Receive Buffer Register	U3RB	XX ₁₆
032F ₁₆			XX ₁₆
0330 ₁₆			
0331 ₁₆			
0332 ₁₆			
0333 ₁₆			
0334 ₁₆	UART2 Special Mode Register 4	U2SMR4	00 ₁₆
0335 ₁₆	UART2 Special Mode Register 3	U2SMR3	00 ₁₆
0336 ₁₆	UART2 Special Mode Register 2	U2SMR2	00 ₁₆
0337 ₁₆	UART2 Special Mode Register	U2SMR	00 ₁₆
0338 ₁₆	UART2 Transmit/Receive Mode Register	U2MR	00 ₁₆
0339 ₁₆	UART2 Bit Rate Register	U2BRG	XX ₁₆
033A ₁₆	UART2 Transmit Buffer Register	U2TB	XX ₁₆
033B ₁₆			XX ₁₆
033C ₁₆	UART2 Transmit/Receive Control Register 0	U2C0	0000 1000 ₂
033D ₁₆	UART2 Transmit/Receive Control Register 1	U2C1	0000 0010 ₂
033E ₁₆	UART2 Receive Buffer Register	U2RB	XX ₁₆
033F ₁₆			XX ₁₆
0340 ₁₆	Count Start Flag	TABSR	00 ₁₆
0341 ₁₆	Clock Prescaler Reset Flag	CPSRF	0XXX XXXX ₂
0342 ₁₆	One-Shot Start Flag	ONSF	00 ₁₆
0343 ₁₆	Trigger Select Register	TRGSR	00 ₁₆
0344 ₁₆	Up/Down Flag	UDF	00 ₁₆
0345 ₁₆			
0346 ₁₆	Timer A0 Register	TA0	XX ₁₆
0347 ₁₆			XX ₁₆
0348 ₁₆	Timer A1 Register	TA1	XX ₁₆
0349 ₁₆			XX ₁₆
034A ₁₆	Timer A2 Register	TA2	XX ₁₆
034B ₁₆			XX ₁₆
034C ₁₆	Timer A3 Register	TA3	XX ₁₆
034D ₁₆			XX ₁₆
034E ₁₆	Timer A4 Register	TA4	XX ₁₆
034F ₁₆			XX ₁₆

X: Indeterminate

Blank spaces are reserved. No access is allowed.

<100-pin Package>

Address	Register	Symbol	Value after RESET
03A0 ₁₆			
03A1 ₁₆			
03A2 ₁₆			
03A3 ₁₆			
03A4 ₁₆			
03A5 ₁₆			
03A6 ₁₆			
03A7 ₁₆	Function Select Register D1	PSD1	X0XX XX00 ₂
03A8 ₁₆			
03A9 ₁₆			
03AA ₁₆			
03AB ₁₆			
03AC ₁₆	Function Select Register C2	PSC2	XXXX X00X ₂
03AD ₁₆	Function Select Register C3	PSC3	X0XX XXXX ₂
03AE ₁₆			
03AF ₁₆	Function Select Register C	PSC	00X0 0000 ₂
03B0 ₁₆	Function Select Register A0	PS0	00 ₁₆
03B1 ₁₆	Function Select Register A1	PS1	00 ₁₆
03B2 ₁₆	Function Select Register B0	PSL0	00 ₁₆
03B3 ₁₆	Function Select Register B1	PSL1	00 ₁₆
03B4 ₁₆	Function Select Register A2	PS2	00X0 0000 ₂
03B5 ₁₆	Function Select Register A3	PS3	00 ₁₆
03B6 ₁₆	Function Select Register B2	PSL2	00X0 0000 ₂
03B7 ₁₆	Function Select Register B3	PSL3	00 ₁₆
03B8 ₁₆			
03B9 ₁₆			
03BA ₁₆			
03BB ₁₆			
03BC ₁₆			
03BD ₁₆			
03BE ₁₆			
03BF ₁₆			
03C0 ₁₆	Port P6 Register	P6	XX ₁₆
03C1 ₁₆	Port P7 Register	P7	XX ₁₆
03C2 ₁₆	Port P6 Direction Register	PD6	00 ₁₆
03C3 ₁₆	Port P7 Direction Register	PD7	00 ₁₆
03C4 ₁₆	Port P8 Register	P8	XX ₁₆
03C5 ₁₆	Port P9 Register	P9	XX ₁₆
03C6 ₁₆	Port P8 Direction Register	PD8	00X0 0000 ₂
03C7 ₁₆	Port P9 Direction Register	PD9	00 ₁₆
03C8 ₁₆	Port P10 Register	P10	XX ₁₆
03C9 ₁₆			
03CA ₁₆	Port P10 Direction Register	PD10	00 ₁₆
03CB ₁₆	Set default value to "FF ₁₆ "		
03CC ₁₆			
03CD ₁₆			
03CE ₁₆	Set default value to "FF ₁₆ "		
03CF ₁₆	Set default value to "FF ₁₆ "		

X: Indeterminate

Blank spaces are reserved. No access is allowed.

Table 5.2 Recommended Operating Conditions**(V_{CC1}= V_{CC2}=3.0V to 5.5V at Topr=– 20 to 85°C unless otherwise specified)**

Symbol	Parameter	Standard			Unit
		Min.	Typ.	Max.	
V _{CC1} , V _{CC2}	Supply Voltage (V _{CC1} ≥ V _{CC2})	3.0	5.0	5.5	V
AV _{CC}	Analog Supply Voltage		V _{CC1}		V
V _{SS}	Supply Voltage		0		V
AV _{SS}	Analog Supply Voltage		0		V
V _{IH}	Input High ("H") Voltage	P20-P27, P30-P37, P40-P47, P50-P57, P110-P114, P120-P127, P130-P137 ⁽⁴⁾	0.8V _{CC2}	V _{CC2}	V
		P60-P67, P72-P77, P80-P87 ⁽³⁾ , P90-P97, P100-P107, P140-P146, P150-P157 ⁽⁴⁾ , X _{IN} , RESET, CNV _{SS} , BYTE	0.8V _{CC1}	V _{CC1}	
		P70, P71	0.8V _{CC1}	6.0	
		P00-P07, P10-P17 (in single-chip mode)	0.8V _{CC2}	V _{CC2}	
		P00-P07, P10-P17 (in memory expansion mode and microprocessor mode)	0.5V _{CC2}	V _{CC2}	
V _{IL}	Input Low ("L") Voltage	P20-P27, P30-P37, P40-P47, P50-P57, P110-P114, P120-P127, P130-P137 ⁽⁴⁾	0	0.2V _{CC2}	V
		P60-P67, P70-P77, P80-P87 ⁽³⁾ , P90-P97, P100-P107, P140-P146, P150-P157 ⁽⁴⁾ , X _{IN} , RESET, CNV _{SS} , BYTE	0	0.2V _{CC1}	
		P00-P07, P10-P17 (in single-chip mode)	0	0.2V _{CC2}	
		P00-P07, P10-P17 (in memory expansion mode and microprocessor mode)	0	0.16V _{CC2}	
I _{OH(peak)}	Peak Output High ("H") Current ⁽²⁾	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P72-P77, P80-P84, P86, P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽⁴⁾		-10.0	mA
I _{OH(avg)}	Average Output High ("H") Current ⁽¹⁾	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P72-P77, P80-P84, P86, P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽⁴⁾		-5.0	mA
I _{OL(peak)}	Peak Output Low ("L") Current ⁽²⁾	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P80-P84, P86, P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽⁴⁾		10.0	mA
I _{OL(avg)}	Average Output Low ("L") Current ⁽¹⁾	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P80-P84, P86, P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽⁴⁾		5.0	mA

NOTES:

1. Typical values when average output current is 100ms.
2. Total I_{OL(peak)} for P0, P1, P2, P86, P87, P9, P10, P11, P14 and P15 must be 80mA or less.
 Total I_{OL(peak)} for P3, P4, P5, P6, P7, P80 to P84, P12 and P13 must be 80mA or less.
 Total I_{OH(peak)} for P0, P1, P2, and P11 must be -40mA or less.
 Total I_{OH(peak)} for P86, P87, P9, P10, P14 and P15 must be -40mA or less.
 Total I_{OH(peak)} for P3, P4, P5, P12 and P13 must be -40mA or less.
 Total I_{OH(peak)} for P6, P7, and P80 to P84 must be -40mA or less.
3. V_{IH} and V_{IL} reference for P87 applies when P87 is used as a programmable input port.
 It does not apply when P87 is used as X_{CIN}.
4. P11 to P15 are provided in the 144-pin package only.

$$V_{CC1}=V_{CC2}=5V$$

**Table 5.6 Flash Memory Version Electrical Characteristics (V_{CC1}=4.5 to 5.5V, 3.3 to 3.6V at
T_{opr}=0 to 60°C unless otherwise specified)**

Symbol	Parameter		Standard			Unit
			Min.	Typ.	Max.	
-	Program and Erase Endurance ⁽²⁾		100			cycles
-	Word Program Time (V _{CC1} =5.0V, T _{opr} =25° C)			25	200	μs
-	Lock Bit Program Time			25	200	μs
-	Block Erase Time (V _{CC1} =5.0V, T _{opr} =25° C)	4-Kbyte Block		0.3	4	s
		8-Kbyte Block		0.3	4	s
		32-Kbyte Block		0.5	4	s
		64-Kbyte Block		0.8	4	s
-	All-Unlocked-Block Erase Time ⁽¹⁾				4 x <i>n</i>	s
t _{PS}	Wait Time to Stabilize Flash Memory Circuit				15	μs
-	Data Hold Time (T _{opr} =-40 to 85 ° C)		10			years

NOTES:

1. *n* denotes the number of block to be erased.

2. Number of program-erase cycles per block.

If Program and Erase Endurance is *n* cycle (*n*≠100), each block can be erased and programmed *n* cycles.

For example, if a 4-Kbyte block A is erased after programming a word data 2,048 times, each to a different address, this counts as one program and erase endurance. Data can not be programmed to the same address more than once without erasing the block. (rewrite prohibited).

$$V_{CC1}=V_{CC2}=5V$$

Timing Requirements

($V_{CC1}=V_{CC2}=4.2$ to $5.5V$, $V_{SS}=0V$ at $T_{opr}=-20$ to $85^{\circ}C$ unless otherwise specified)

Table 5.9 External Clock Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
t_c	External Clock Input Cycle Time	31.25		ns
$t_{w(H)}$	External Clock Input High ("H") Width	13.75		ns
$t_{w(L)}$	External Clock Input Low ("L") Width	13.75		ns
t_r	External Clock Rise Time		5	ns
t_f	External Clock Fall Time		5	ns

Table 5.10 Memory Expansion Mode and Microprocessor Mode

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{ac1(RD-DB)}$	Data Input Access Time (RD standard)		(Note 1)	ns
$t_{ac1(AD-DB)}$	Data Input Access Time (AD standard, CS standard)		(Note 1)	ns
$t_{ac2(RD-DB)}$	Data Input Access Time (RD standard, when accessing a space with the multiplexrd bus)		(Note 1)	ns
$t_{ac2(AD-DB)}$	Data Input Access Time (AD standard, when accessing a space with the multiplexed bus)		(Note 1)	ns
$t_{su(DB-BCLK)}$	Data Input Setup Time	26		ns
$t_{su(RDY-BCLK)}$	$\overline{RDY}$ Input Setup Time	26		ns
$t_{su(HOLD-BCLK)}$	$\overline{HOLD}$ Input Setup Time	30		ns
$t_{h(RD-DB)}$	Data Input Hold Time	0		ns
$t_{h(BCLK-RDY)}$	$\overline{RDY}$ Input Hold Time	0		ns
$t_{h(BCLK-HOLD)}$	$\overline{HOLD}$ Input Hold Time	0		ns
$t_{d(BCLK-HLDA)}$	$\overline{HLDA}$ Output Delay Time		25	ns

NOTES:

- Values can be obtained from the following equations, according to BCLK frequency and external bus cycles. Insert a wait state or lower the operation frequency, $f_{(BCLK)}$, if the calculated value is negative.

$$t_{ac1(RD-DB)} = \frac{10^9 \times m}{f_{(BCLK)} \times 2} - 35 \quad [\text{ns}] \text{ (if external bus cycle is } a\phi + b\phi, m=(bx2)+1)$$

$$t_{ac1(AD-DB)} = \frac{10^9 \times n}{f_{(BCLK)}} - 35 \quad [\text{ns}] \text{ (if external bus cycle is } a\phi + b\phi, n=a+b)$$

$$t_{ac2(RD-DB)} = \frac{10^9 \times m}{f_{(BCLK)} \times 2} - 35 \quad [\text{ns}] \text{ (if external bus cycle is } a\phi + b\phi, m=(bx2)-1)$$

$$t_{ac2(AD-DB)} = \frac{10^9 \times p}{f_{(BCLK)} \times 2} - 35 \quad [\text{ns}] \text{ (if external bus cycle is } a\phi + b\phi, p=\{(a+b-1) \times 2\}+1)$$

$$V_{CC1}=V_{CC2}=3.3V$$

Timing Requirements

($V_{CC1}=V_{CC2}=3.0$ to $3.6V$, $V_{SS}=0V$ at $T_{opr}=-20$ to $85^{\circ}C$ unless otherwise specified)

Table 5.34 Timer B Input (Count Source Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(TB)}$	TBiIN Input Cycle Time (counted on one edge)	100		ns
$t_{W(TBH)}$	TBiIN Input High ("H") Width (counted on one edge)	40		ns
$t_{W(TBL)}$	TBiIN Input Low ("L") Width (counted on one edge)	40		ns
$t_{C(TB)}$	TBiIN Input Cycle Time (counted on both edges)	200		ns
$t_{W(TBH)}$	TBiIN Input High ("H") Width (counted on both edges)	80		ns
$t_{W(TBL)}$	TBiIN Input Low ("L") Width (counted on both edges)	80		ns

Table 5.35 Timer B Input (Pulse Period Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(TB)}$	TBiIN Input Cycle Time	400		ns
$t_{W(TBH)}$	TBiIN Input High ("H") Width	200		ns
$t_{W(TBL)}$	TBiIN Input Low ("L") Width	200		ns

Table 5.36 Timer B Input (Pulse Width Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(TB)}$	TBiIN Input Cycle Time	400		ns
$t_{W(TBH)}$	TBiIN Input High ("H") Width	200		ns
$t_{W(TBL)}$	TBiIN Input Low ("L") Width	200		ns

Table 5.37 A/D Trigger Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(AD)}$	$\overline{AD_{TRG}}$ Input Cycle Time (required for trigger)	1000		ns
$t_{W(ADL)}$	$\overline{AD_{TRG}}$ Input Low ("L") Width	125		ns

Table 5.38 Serial I/O

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(CK)}$	CLKi Input Cycle Time	200		ns
$t_{W(CKH)}$	CLKi Input High ("H") Width	100		ns
$t_{W(CKL)}$	CLKi Input Low ("L") Width	100		ns
$t_{d(C-Q)}$	TxDi Output Delay Time		80	ns
$t_{h(C-Q)}$	TxDi Hold Time	0		ns
$t_{su(D-C)}$	RxDi Input Setup Time	30		ns
$t_{h(C-Q)}$	RxDi Input Hold Time	90		ns

Table 5.39 External Interrupt $\overline{INTi}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{W(INH)}$	$\overline{INTi}$ Input High ("H") Width	250		ns
$t_{W(INL)}$	$\overline{INTi}$ Input Low ("L") Width	250		ns

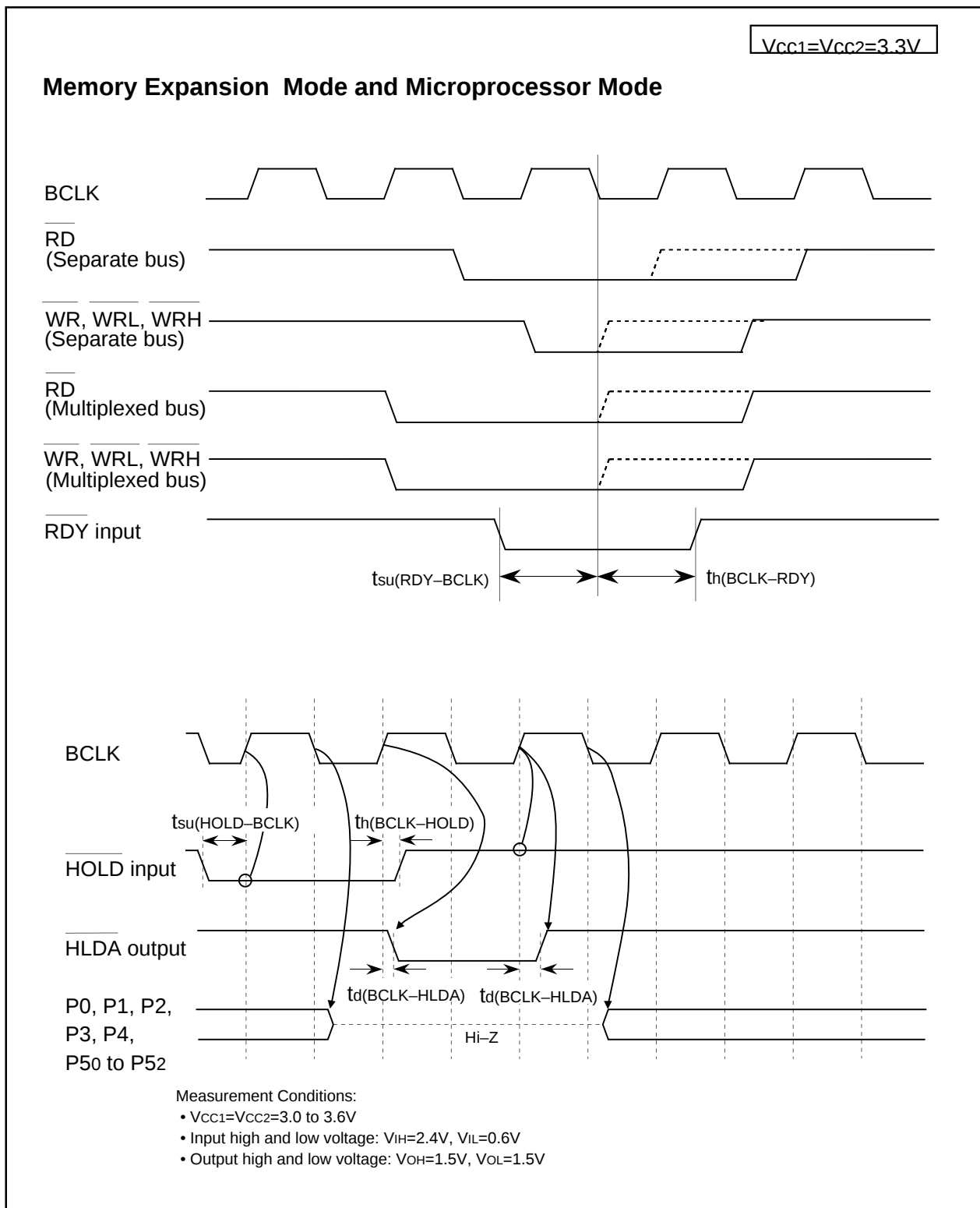
Figure 5.10 $V_{CC1}=V_{CC2}=3.3V$ Timing Diagram (4)

Table 5.43 Recommended Operating Conditions (Continued)**(V_{CC1}=V_{CC2}=4.2 to 5.5V, V_{SS}=0V at T_{opr} = -40 to 85°C (T version) unless otherwise specified)**

Symbol	Parameter		Standard			Unit
			Min.	Typ.	Max.	
f(BCLK)	CPU Input Frequency	V _{CC1} =4.2 to 5.5V	0		32	MHz
f(X _{IN})	Main Clock Input Frequency	V _{CC1} =4.2 to 5.5V	0		32	MHz
f(X _{CIN})	Sub Clock Frequency			32.768	50	kHz
f(Ring)	On-chip Oscillator Frequency (V _{CC1} =V _{CC2} =5.0V, T _{opr} =25° C)		0.5	1	2	MHz
f(PLL)	PLL Clock Frequency	V _{CC1} =4.2 to 5.5V	10		32	MHz
t _{SU(PLL)}	Wait Time to Stabilize PLL Frequency Synthesizer	V _{CC1} =5.0V			5	ms

$$V_{CC1}=V_{CC2}=5V$$

Table 5.44 Electrical Characteristics

($V_{CC1}=V_{CC2}=4.2$ to $5.5V$, $V_{SS}=0V$ at $T_{opr} = -40$ to $85^{\circ}C$ (T version),
 $f(BCLK)=32MHz$ unless otherwise specified)

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
V _{OH}	Output High ("H") Voltage	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P110-P114, P120-P127, P130-P137	I _{OH} =-5mA	V _{CC2} -2.0	V _{CC2}	V
		P60-P67, P72-P77, P80-P84, P86, P87, P90-P97, P100-P107, P140-P146, P150-P157 ⁽¹⁾	I _{OH} =-5mA	V _{CC1} -2.0	V _{CC1}	
		P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P110-P114, P120-P127, P130-P137	I _{OH} =-200μA	V _{CC2} -0.3	V _{CC2}	V
		P60-P67, P72-P77, P80-P84, P86, P87, P90-P97, P100-P107, P140-P146, P150-P157 ⁽¹⁾	I _{OH} =-200μA	V _{CC1} -0.3	V _{CC1}	
		X _{OUT}	I _{OH} =-1mA	3.0		V
		X _{COUT}	High Power	No load applied	2.5	V
			Low Power	No load applied	1.6	
V _{OL}	Output Low ("L") Voltage	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P80-P84, P86, P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾	I _{OL} =5mA		2.0	V
		P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P80-P84, P86, P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾	I _{OL} =200μA		0.45	V
		X _{OUT}	I _{OL} =1mA		2.0	V
		X _{COUT}	High Power	No load applied	0	V
			Low Power	No load applied	0	
V _{T+} -V _{T-}	Hysteresis	HOLD, RDY, TA0IN-TA4IN, TB0IN-TB5IN, INT0-INT5, ADTRG, CTS0-CTS4, CLK0-CLK4, TA0OUT-TA4OUT, NMI, K10-K13, RxD0-RxD4, SCL0-SCL4, SDA0-SDA4		0.2	1.0	V
		RESET		0.2	1.8	V
I _{IH}	Input High ("H") Current	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P80-P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾ , X _{IN} , RESET, CNVSS, BYTE	V _I =5V		5.0	μA
I _{IL}	Input Low ("L") Current	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P70-P77, P80-P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾ , X _{IN} , RESET, CNVSS, BYTE	V _I =0V		-5.0	μA
R _{PULLUP}	Pull-up Resistance	P00-P07, P10-P17, P20-P27, P30-P37, P40-P47, P50-P57, P60-P67, P72-P77, P80-P84, P86, P87, P90-P97, P100-P107, P110-P114, P120-P127, P130-P137, P140-P146, P150-P157 ⁽¹⁾	V _I =0V Flash Memory	30	50	167 kΩ
R _{fXIN}	Feedback Resistance	X _{IN}			1.5	MΩ
R _{fXCIN}	Feedback Resistance	X _{CIN}			10	MΩ
V _{RAM}	RAM Standby Voltage	In stop mode		2.0		V

NOTES:

1. P11 to P15 are provided in the 144-pin package only.

$$V_{CC1}=V_{CC2}=5V$$

Table 5.47 Flash Memory Version Electrical Characteristics(V_{CC1}=4.5 to 5.5V, 3.3 to 3.6V at T_{opr}= 0 to 60°C unless otherwise specified)

Symbol	Parameter		Standard			Unit
			Min.	Typ.	Max.	
-	Program and Erase Endurance ⁽²⁾		100			cycles
-	Word Program Time (V _{CC1} =5.0V, T _{opr} =25° C)			25	200	μs
-	Lock Bit Program Time			25	200	μs
-	Block Erase Time (V _{CC1} =5.0V, T _{opr} =25° C)	4-Kbyte Block		0.3	4	s
		8-Kbyte Block		0.3	4	s
		32-Kbyte Block		0.5	4	s
		64-Kbyte Block		0.8	4	s
-	All-Unlocked-Block Erase Time ⁽¹⁾				4 x <i>n</i>	s
t _{PS}	Wait Time to Stabilize Flash Memory Circuit				15	μs
-	Data Hold Time (T _{opr} =-40 to 85 ° C)		10			years

NOTES:

1. *n* denotes the number of block to be erased.

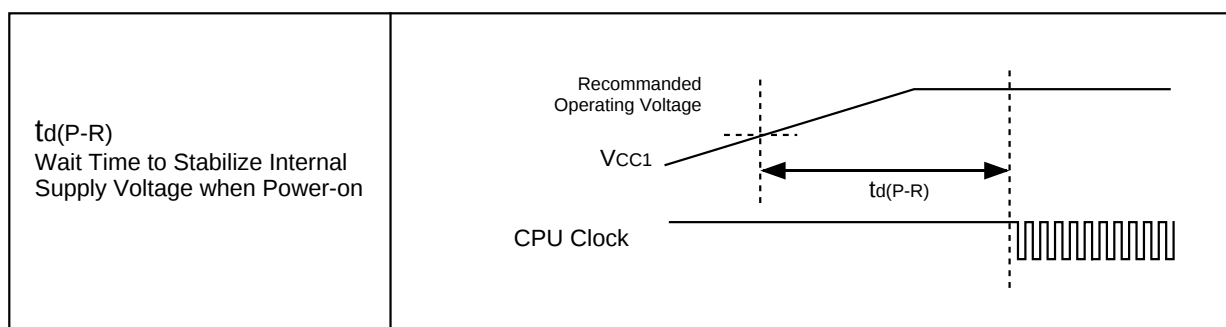
2. Number of program-erase cycles per block.

If Program and Erase Endurance is *n* cycle (*n*≠100), each block can be erased and programmed *n* cycles.

For example, if a 4-Kbyte block A is erased after programming a word data 2,048 times, each to a different address, this counts as one program and erase endurance. Data can not be programmed to the same address more than once without erasing the block. (rewrite prohibited).

Table 5.48 Power Supply Timing

Symbol	Parameter	Measurement Condition	Standard			Unit
			Min.	Typ.	Max.	
t _{d(P-R)}	Wait Time to Stabilize Internal Supply Voltage when Power-on	V _{CC1} =3.0 to 5.5V			2	ms

**Figure 5.11 Power Supply Timing Diagram**

$$V_{CC1}=V_{CC2}=5V$$

Timing Requirements

($V_{CC1}=V_{CC2}=4.2$ to $5.5V$, $V_{SS}=0V$ at $T_{opr}= -40$ to $85^{\circ}C$ (T version) unless otherwise specified)

Table 5.55 Timer B Input (Count Source Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(TB)}$	TB _{IN} Input Cycle Time (counted on one edge)	100		ns
$t_{W(TBH)}$	TB _{IN} Input High ("H") Width (counted on one edge)	40		ns
$t_{W(TBL)}$	TB _{IN} Input Low ("L") Width (counted on one edge)	40		ns
$t_{C(TB)}$	TB _{IN} Input Cycle Time (counted on both edges)	200		ns
$t_{W(TBH)}$	TB _{IN} Input High ("H") Width (counted on both edges)	80		ns
$t_{W(TBL)}$	TB _{IN} Input Low ("L") Width (counted on both edges)	80		ns

Table 5.56 Timer B Input (Pulse Period Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(TB)}$	TB _{IN} Input Cycle Time	400		ns
$t_{W(TBH)}$	TB _{IN} Input High ("H") Width	200		ns
$t_{W(TBL)}$	TB _{IN} Input Low ("L") Width	200		ns

Table 5.57 Timer B Input (Pulse Width Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(TB)}$	TB _{IN} Input Cycle Time	400		ns
$t_{W(TBH)}$	TB _{IN} Input High ("H") Width	200		ns
$t_{W(TBL)}$	TB _{IN} Input Low ("L") Width	200		ns

Table 5.58 A/D Trigger Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(AD)}$	AD _{TRG} Input Cycle Time (required for trigger)	1000		ns
$t_{W(ADL)}$	AD _{TRG} Input Low ("L") Pulse Width	125		ns

Table 5.59 Serial I/O

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{C(CK)}$	CLK _I Input Cycle Time	200		ns
$t_{W(CKH)}$	CLK _I Input High ("H") Width	100		ns
$t_{W(CKL)}$	CLK _I Input Low ("L") Width	100		ns
$t_{d(C-Q)}$	TxD _I Output Delay Time		80	ns
$t_{h(C-Q)}$	TxD _I Hold Time	0		ns
$t_{su(D-C)}$	RxD _I Input Setup Time	30		ns
$t_{h(C-Q)}$	RxD _I Input Hold Time	90		ns

Table 5.60 External Interrupt INT_I Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{W(INH)}$	INT _I Input High ("H") Width	250		ns
$t_{W(INL)}$	INT _I Input Low ("L") Width	250		ns

REVISION HISTORY	M32C/84 Group (M32C/84, M32C/84T) Datasheet
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Rev.	Date	Description	
		Page	Summary
0.40	Sep. 30, 2003	—	New Document
0.50	Feb. 05, 2004	2, 3	Overview • Table 1.1 and Table 1.2 M32C/84 Group Performance Values for Shortest Instruction Execution Time and Power Consumption” modified
		5	• Figure 1.2 ROM/RAM Capacity Products added
		6	• Table 1.3 M32C/84 Group Products added
		6	• Figure 1.3 Product Numbering System 128-Kbytes added to ROM capacity Memory
0.50	Feb. 05, 2004	23	• Figure 3.1 Memory Map Diagram modified; products added
		24	SFR • “Values after RESET” for the PM1, PM2, D4INT, G0IRF, G1IRF, IDB0 to IDB1, TA0MR to TA4MR, TCSPR, DM0SL to DM3SL registers revised • The IPSA register added to address 0179 ₁₆ • NOTES added to the PM0 and TCSPR register
		44	Electrical Characteristics • Newly added
0.51	Feb. 09, 2004		Electrical Characteristics
		50	• Table 5.6 Flash Memory Version Electrical Characteristics Note 4 revised
		57	• Figure 5.2 Vcc1=Vcc2=5V Timing Diagram (1) Notes 1 and 2 revised
		68	• Figure 5.3 Vcc1=Vcc2=5V Timing Diagram (2) Notes 1, 2, and 3 revised
		68	• Figure 5.6 Vcc1=Vcc2=3.3V Timing Diagram (1) Notes 1, 2, and 3 revised
0.51	Feb. 09, 2004	69	• Figure 5.7 Vcc1=Vcc2=3.3V Timing Diagram (2) Notes 1 and 2 revised
0.52	Mar.12, 2004		Overview
		2, 3	• Table 1.1 and 1.2 M32C/84 Group Performance Values for Power Consumption modified
		48	Electrical Characteristics • Table 5.3 Electrical Characteristics Maximum values for Power Supply Current modified
		50	• Table 5.6 Flash Memory Version Electrical Characteristics Note 1. 100-cycle Products (D3, D5, U3, U5) deleted; Note 4 modified
0.52	Mar.12, 2004		• Table 5.7 Flash Memory Version Program and Erase Voltage and Read Operation Voltage Characteristics (at Topr=0 to 60°C) deleted
		61	• Table 5.22 Electrical Characteristics Maximum values for Power Supply Consumption modified and standard values when “Topr=85°C while clock is stopped” deleted

